



Complete 12-Bit 10 MSPS Monolithic A/D Converter

SMD/883B

AD872A

Scope

This specification covers the detail requirements for a complete monolithic 12-bit, 10 MSPS A/D converter with an on-chip, high performance track-and-hold amplifier (THA) and voltage reference. The electrical specifications match the Standard Microcircuit Drawing (SMD) 5962-93060 in effect at the release of this data sheet. For a copy of the latest official SMD, contact DESC-ELDS.

Part Number/Case Outline

For case outline dimensions, see Package Information Appendix of General Specification ADI-M-1000. The complete part numbers of these SMD and 883 devices are as follows:

Device Type	SMD Part Number	ADI 883B Part Number	Package Description	Package Designation ADI MIL-STD-1835
01	5962-9306001MXA	AD872ASD/883B	28-Pin Side Brazed DIP	D-28 CDIP2-T28
02	5962-9306002MYA	AD872ASE/883B	44-Terminal LCC	E-44A CQCCI-N44

Absolute Maximum Ratings ($T_A = +25^\circ\text{C}$ unless otherwise noted)¹

AV_{DD} to AGND	−0.5 V to +6.5 V
AV_{SS} to AGND	−6.5 V to +0.5 V
DV_{DD} , DRV_{DD}^2 to DGND, DRGND ²	−0.5 V to +6.5 V
DRV_{DD} to DV_{DD}^2	−6.5 V to +6.5 V
DRGND to DGND ²	−0.3 V to +0.3 V
AGND to DGND	−1 V to +1 V
AV_{DD} to DV_{DD}	−6.5 V to +6.5 V
Clock Input, OEN^2 to DGND	−0.5 V to $DV_{DD} + 0.5$ V
Digital Outputs to DGND	−0.5 V to $DV_{DD} + 0.3$ V
REF IN to AGND	AV_{SS} to AV_{DD}
V_{INA} , to V_{INB} , REF IN to AGND	−6.5 V to +6.5 V
Storage Temperature Range	−65°C to +150°C
Lead Temperature (Soldering 10 sec)	+300°C

Recommended Operating Conditions²

Operating Ambient Temperature Range	−55°C to +125°C
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Thermal Characteristics

Thermal Resistance, Junction-to-Case (θ_{JC}) for D-28	28°C/W
Thermal Resistance, Junction-to-Ambient (θ_{JA}) for D-28	60°C/W
Thermal Resistance, Junction-to-Case (θ_{JC}) for E-44A	20°C/W
Thermal Resistance, Junction-to-Ambient (θ_{JA}) for E-44A	70°C/W

NOTES

¹Permanent damage may occur if any absolute maximum rating is exceeded. Functional operation is not implied and device reliability may be impaired by exposure to higher-than-recommended voltages for extended periods of time.

²Device Type 02 only.

REV. B

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AD872A—SPECIFICATIONS

Table 1. Electrical Performance Characteristics

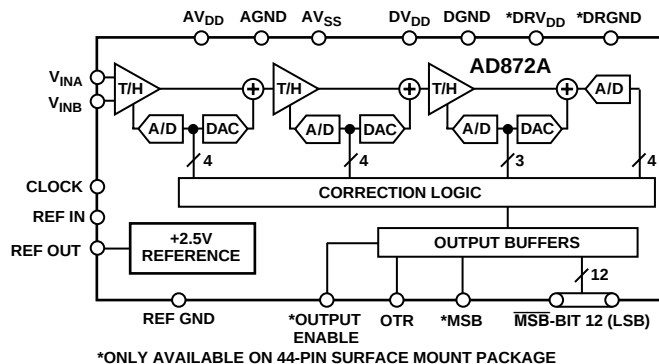
Test	Symbol	Conditions $AV_{DD} = +5\text{ V}$, $AV_{SS} = -5\text{ V}$, $DV_{DD} = +5\text{ V}$, $DRV_{DD} = +5\text{ V}$ unless otherwise specified	Group A Subgroups	Device Type	Limits		Units
					Min	Max	
Resolution	RES		1, 2, 3	01, 02	12		Bits
Differential Nonlinearity ¹	DNL	All Codes Histogram	1, 2, 3	01, 02	12		Bits
Zero Error	B _{POE}		1	01, 02		0.75	±% FSR
Gain Error	A _E		1	01, 02		1.25	±% FSR
Zero Error Drift	TCB _{POE}	External 2.5 V Reference	2, 3	01, 02		0.30	±% FSR
Gain Error Drift	TCA _{INT}	Internal 2.5 V Reference	2, 3	01, 02		1.75	±% FSR
Gain Error Drift	TCA _{EXT}	External 2.5 V Reference	2, 3	01, 02		0.5	±% FSR
Power Supply Rejection	PSR	See Note 2	1, 2, 3	01, 02		0.125	±% FSR
Analog Input Range	V _{IN}		1, 2, 3	01, 02		1	±V
Input Resistance	R _{IN}	T _A = +25°C		01, 02	50 typ		kΩ
Input Capacitance	C _{IN}	T _A = +25°C		01, 02	10 typ		pF
Internal Reference Output Voltage	V _{REF}		1, 2, 3	01, 02	2.46	2.54	V
Power Dissipation	PD		1, 2, 3	01, 02		1.3	W
Power Supply Current	IAV _{DD}		1, 2, 3	01, 02		92	mA
	IAV _{SS}					150	
	IDV _{DD}					21	
	IDRV _{DD}		02			2	
Signal-to-Noise and Distortion Ratio	S/(N + D)	f _{IN} = 1 MHz; f _s = 10 MHz	1, 2, 3	01	61		dB
				02	60		
Total Harmonic Distortion	THD	f _{IN} = 1 MHz; f _s = 10 MHz	1, 2, 3	01		−62	dB
				02		−60	
Logic Input High Voltage	V _{IH}		1, 2, 3	01, 02	2.0		V
Logic Input Low Voltage	V _{IL}		1, 2, 3	01, 02		0.8	V
Logic Input High Current (CLK)	I _{IH}		1, 2, 3	01		115	±μA
Logic Input Low Current (CLK)	I _{IL}		1, 2, 3	01		115	±μA
Logic Input High Current (OEN, CLK)	I _{IH}		1, 2, 3	02		115	±μA
Logic Input Low Current (OEN, CLK)	I _{IL}		1, 2, 3	02		115	±μA
Logic Output High Voltage ($\overline{\text{MSB}}$ —Bit 12, OTR)	V _{OH}	I _{SOURCE} = 500 μA	1, 2, 3	01, 02	2.4		V
Logic Output Low Voltage ($\overline{\text{MSB}}$ —Bit 12, OTR)	V _{OL}	I _{SINK} = 1.6 mA	1, 2, 3	01, 02		0.4	V
Leakage	I _Z	Three State	1, 2, 3	02		10	±μA
Clock Period	t _C	See Figure 1.	9, 10, 11	01, 02	100		ns
Output Delay	t _{OD}	See Figure 1.	9, 10, 11	01, 02	10		ns

NOTES

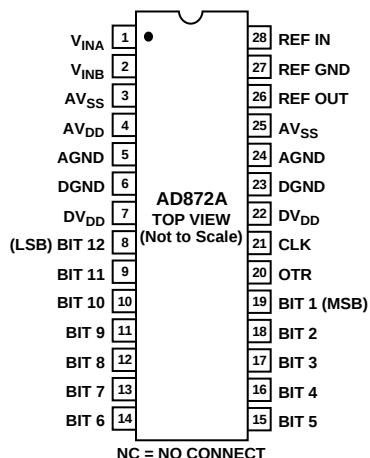
¹Minimum resolution for which “No Missing Codes” is guaranteed.

²Test conditions for PSR: 4.75 V ≤ AV_{DD} ≤ 5.25 V, −5.25 V ≤ AV_{SS} ≤ −4.75 V, 4.75 V ≤ DV_{DD} ≤ 5.25 V.

Functional Block Diagram and Terminal Assignment



D-28 Package



E-44A Package

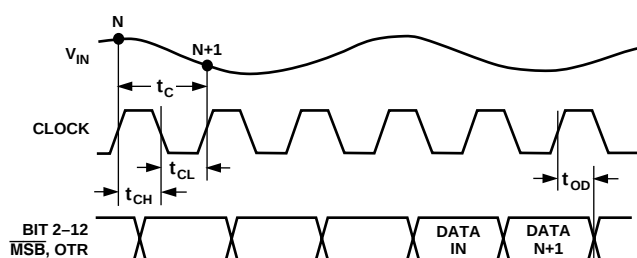
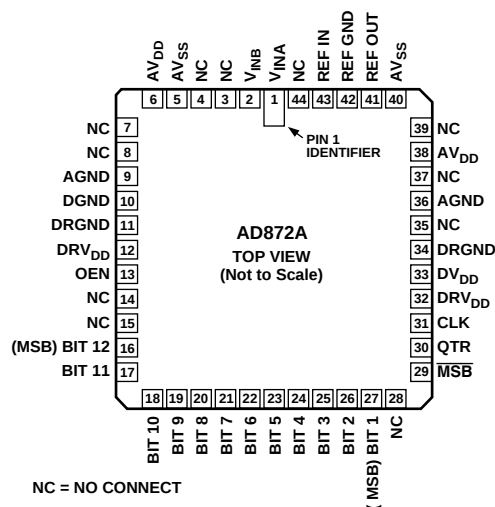


Figure 1. Timing Diagram

SWITCHING SPECIFICATIONS

(T_{MIN} to T_{MAX} with $AV_{DD} = +5V$, $DV_{DD} = +5V$, $DRV_{DD} = +5V$, $AV_{SS} = -5V$; $V_{IL} = 0.8V$, $V_{IH} = 2.0V$. These characteristics are included for design guidance only and are not tested or guaranteed.)

Parameter	Symbol	Limits	Units
CLOCK Pulse Width High	t_{CH}	45	ns min
CLOCK Pulse Width Low	t_{CL}	45	ns min
Clock Duty Cycle		40	% min (50% typ)
		60	% max
Pipeline Delay (Latency)		3	Clock Cycles

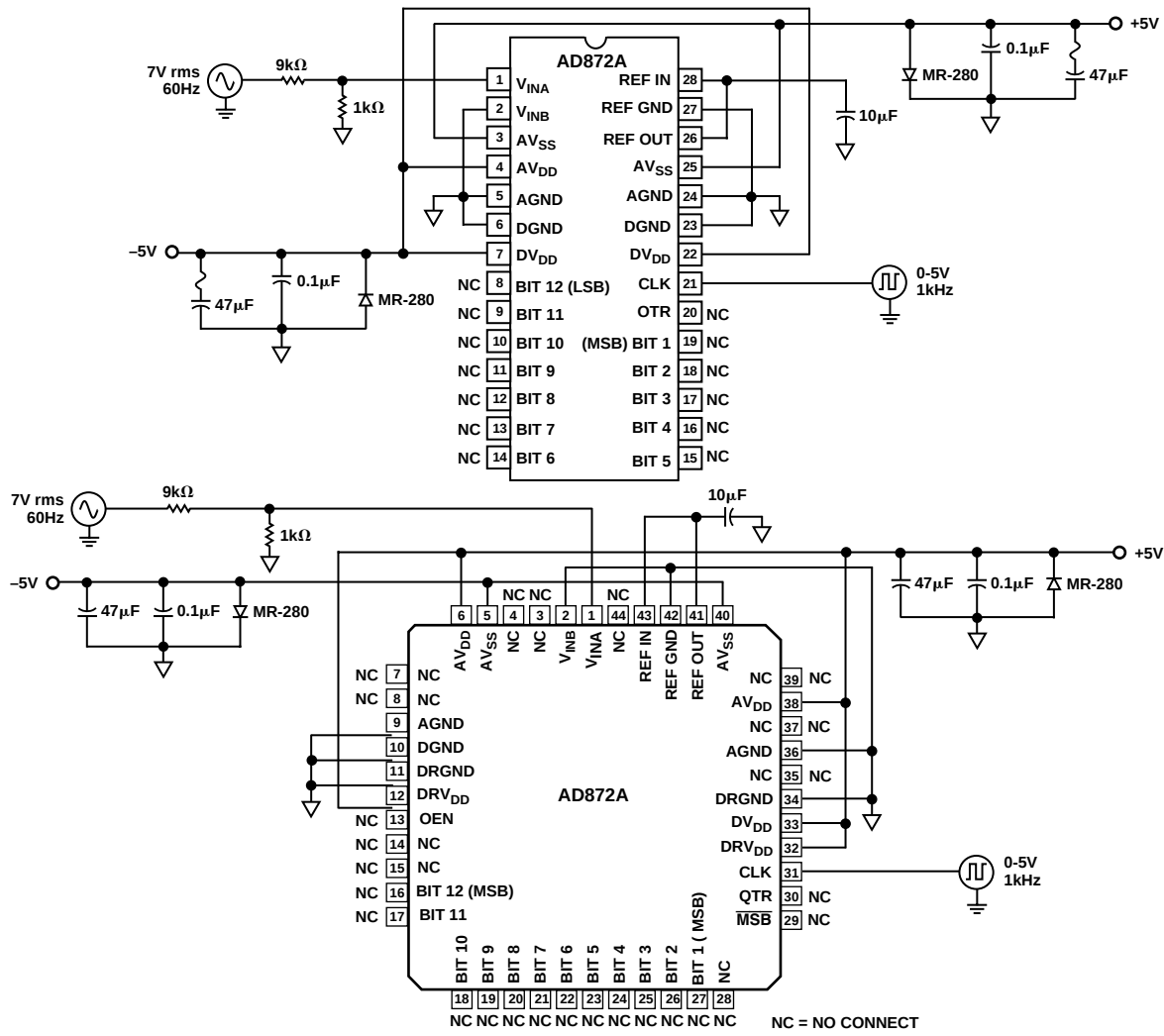
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Microcircuit Technology Group

This microcircuit is covered by technology group (93).

Life Test /Burn-In Circuit

Steady state life test is per MIL-STD-883 Method 1005. Burn-in is per MIL-STD-883 Method 1015 test condition (B).

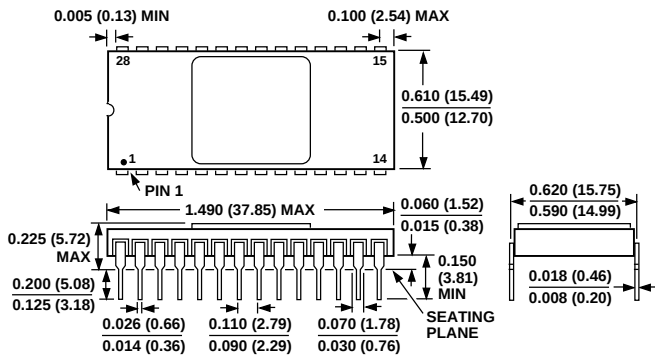


OUTLINE DIMENSIONS

Dimensions shown in inches and (mm).

D-28

28-Lead Side Brazed DIP



E-44A

44-Terminal Ceramic Leadless Chip Carrier

